

# 8-BIT OTPROM FAMILY

(Am2764A, Am27128A, Am27256)

## DISTINCTIVE CHARACTERISTICS

- Fast access times — as low as 200 ns
- Low-power dissipation
- Both interactive and new Flashrite\* programming algorithms available
- Single +5-V power supply
- TTL-compatible inputs and outputs
- $\pm 10\%$  power-supply tolerance available
- Programming voltage—12.5 V

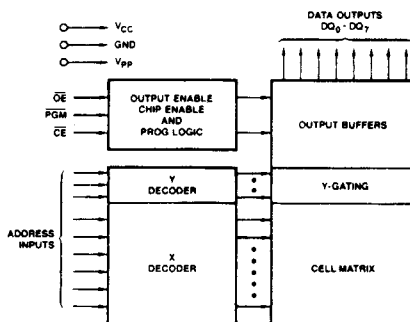
## GENERAL DESCRIPTION

The Am2764A, Am27128A, and the Am27256 are One-Time Programmable Read-Only Memories (OTPROMs) and are organized as 8 bits per word. The plastic OTPROMs are ideal for volume production. First, because they can be inventoried unprogrammed and used with current-level software revisions; second, there is no window to be covered to prevent light from changing data —this could eliminate a manufacturing step and increase the reliability of the system; and third, they are compatible with auto insertion equipment. All standard OTPROMs offer access times of 250 ns, allowing operation with high-speed microprocessors without any Wait states. Some of AMD's OTPROMs have access times of as fast as 200 ns.

To eliminate bus contention on a multiple-bus microprocessor system, all AMD OTPROMs offer separate output enable ( $\overline{OE}$ ) and chip enable ( $\overline{CE}$ ) controls.

All signals are TTL levels, including programming signals. Bit locations may be programmed singly, in blocks, or at random. To reduce programming time, AMD's OTPROMs may be programmed using the Flashrite programming algorithm, which offers several fold improvement in programming time.

## BLOCK DIAGRAM



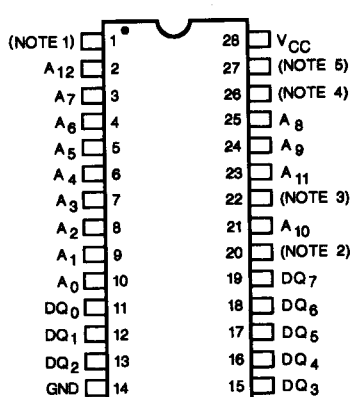
BD000231

## PRODUCT SELECTOR GUIDE

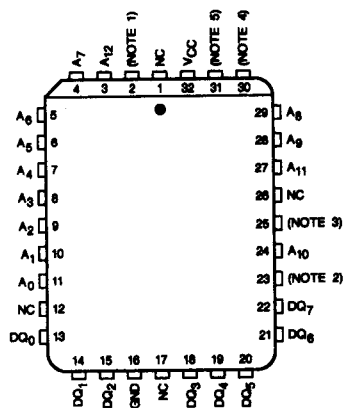
| Family Part No.             | Am2764A, Am27128A, Am27256        |                                   |                                |
|-----------------------------|-----------------------------------|-----------------------------------|--------------------------------|
| Ordering Part No.:          |                                   |                                   |                                |
| $\pm 5\% V_{CC}$ Tolerance  | 2764A-2<br>27128A-2<br>27256-2    | 2764A<br>27128A<br>27256          | 2764A-4<br>27128A-4<br>27256-4 |
| $\pm 10\% V_{CC}$ Tolerance | 2764A-20<br>27128A-20<br>27256-20 | 2764A-25<br>27128A-25<br>27256-25 | —<br>—<br>—                    |
| $t_{ACC}$ (ns)              | 200                               | 250                               | 450                            |
| $t_{CE}$ (ns)               | 200                               | 250                               | 450                            |
| $t_{OE}$ (ns)               | 75                                | 100                               | 150                            |

\*Flashrite is a trademark of Advanced Micro Devices, Inc.

# **CONNECTION DIAGRAMS** **Top View**



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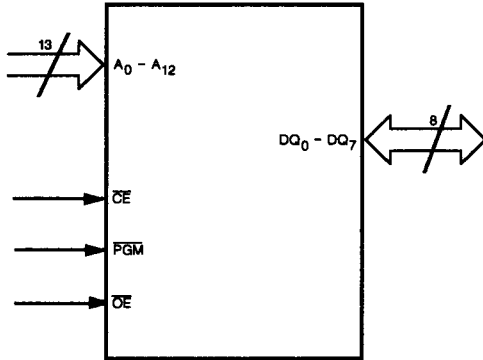


CD009770

| Notes: | Am2764A | Am27128A        | Am27256         |
|--------|---------|-----------------|-----------------|
|        | 1       | V <sub>PP</sub> | V <sub>PP</sub> |
| 2      | CE      | CE              | CE/PGM          |
|        | 3       | OE              | OE              |
| 4      | NC      | A <sub>13</sub> | A <sub>13</sub> |
|        | 5       | PGM             | A <sub>14</sub> |

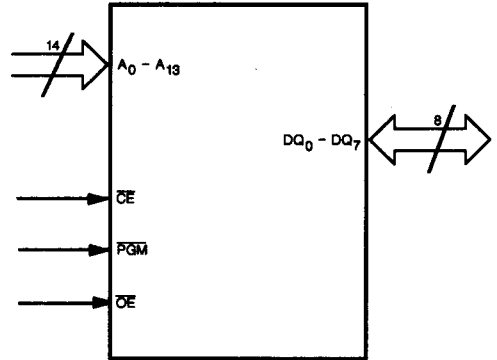
## LOGIC SYMBOLS

**Am2764A**



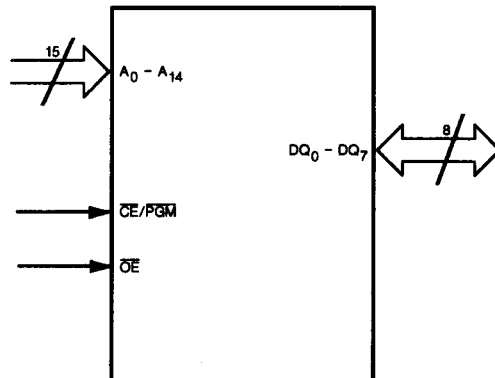
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**Am27128A**



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**Am27256**



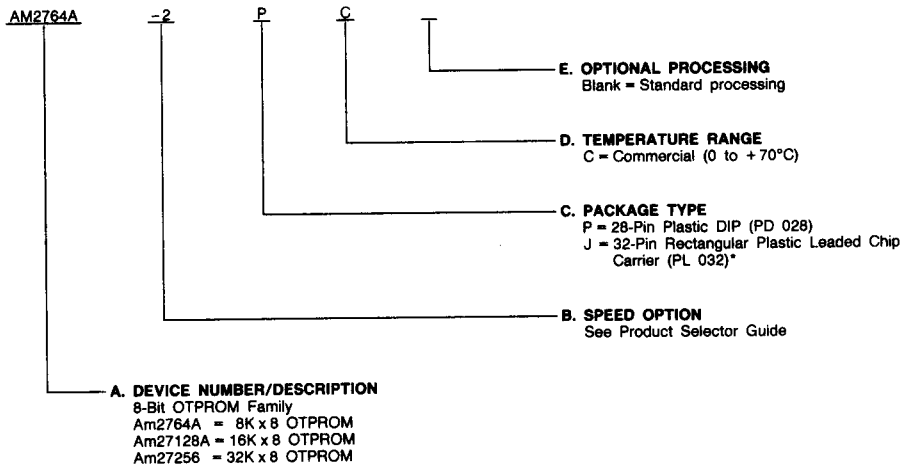
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## ORDERING INFORMATION

### Standard Products

AMD standard products are available in several packages and operating ranges. The order number (Valid Combination) is formed by a combination of:

- A. Device Number**
- B. Speed Option** (if applicable)
- C. Package Type**
- D. Temperature Range**
- E. Optional Processing**



### Valid Combinations

Valid Combinations list configurations planned to be supported in volume for this device. Consult the local AMD sales office to confirm availability of specific valid combinations, to check on newly released valid combinations, and to obtain additional data on AMD's standard military grade products.

\*Preliminary. Subject to Change.

| Valid Combinations              |        |
|---------------------------------|--------|
| ±5% V <sub>CC</sub> Tolerance   |        |
| AM2764A-2                       | PC, JC |
| AM2764A                         |        |
| AM2764A-4                       |        |
| AM27128A-2                      |        |
| AM27128A                        |        |
| AM27128A-4                      |        |
| AM27256-2                       |        |
| AM27256                         |        |
| AM27256-4                       |        |
| ± 10% V <sub>CC</sub> Tolerance |        |
| AM2764A-20                      | PC, JC |
| AM2764A-25                      |        |
| AM27128A-20                     |        |
| AM27128A-25                     |        |
| AM27256-20                      |        |
| AM27256-25                      |        |

## FUNCTIONAL DESCRIPTION

### Programming the 8-Bit OTPROMs

Upon delivery, or after each erasure, the OTPROM has all bits in the "1", or HIGH state. Zeros ("0s") are loaded into the OTPROM through the procedure of programming.

The programming mode is entered when a voltage greater than 12.0, but less than 13.3 V, is applied to the  $V_{pp}$  pin and  $\overline{PGM}$  ( $\overline{CE/PGM}$  for 256K) is low. The data to be programmed is applied 8 bits in parallel to the Data I/O ( $DQ_n$ ) pins.

The flowcharts (Figures 1 and 2) show AMD's Flashrite programming and interactive programming algorithms. The Flashrite programming algorithm improves the programming time by several folds as compared to the interactive algorithm.

The AMD Flashrite programming algorithm reduces programming time by using initial 100  $\mu$ s pulses followed by a byte verification to determine whether the byte has been successfully programmed. If the data does not verify, an additional pulse is applied for a maximum of 25 pulses. This process is repeated while sequencing through each address of the OTPROM.

The Flashrite programming algorithm is programmed and verified at  $V_{CC} = 6.25$  V and  $V_{pp} = 13.0$  V. After the final address is completed, all bytes are compared to the original data with  $V_{CC} = V_{pp} = 5.25$  V.

In addition to the Flashrite programming algorithm, OTPROMs are also compatible with AMD's interactive programming algorithm (see Figure 1).

The programming mode is entered when a voltage greater than 12.0 V but less than 13.3 V is applied to the  $V_{pp}$  pin.

The AMD interactive algorithm uses short (1 ms) program pulses by giving each address only as many pulses as necessary to program the data. After each pulse is applied to a given address, data in that address is verified. If the data does not verify, an additional pulse is applied for a maximum of 25 pulses. This process is repeated while sequencing through each address of the OTPROM. Programming and verification are done at  $V_{CC} = 6.0$  V  $\pm 5\%$ .

The overprogram section of the algorithm programs the entire array by cycling through each address and applying an additional 2-ms program pulse. This section is done at  $V_{CC} = 5.0$  V  $\pm 5\%$ .

After the final address is completed, the entire OTPROM is verified at  $V_{CC} = 5.0$  V  $\pm 5\%$ .

### Auto Select Mode

The Auto Select mode allows the reading out of a binary code from an OTPROM that will identify its manufacturer and type. This mode is intended for use by programming equipment for the purpose of automatically matching the device to be programmed with its corresponding programming algorithm. This mode is functional in the  $25^\circ\text{C} \pm 5^\circ\text{C}$  ambient-temperature range required when programming the OTPROMs.

To activate this mode, the programming equipment must force 12.0 V to  $\pm 0.5$  V on address line  $A_9$ . Two identifier bytes may then be sequenced from the device outputs by toggling address line  $A_0$  from  $V_{IL}$  to  $V_{IH}$ . All other address lines must be held at  $V_{IL}$  during Auto Select mode.

Byte 0 ( $A_0 = V_{IL}$ ,  $DQ_0 - DQ_7$ ) represents the manufacturer code, and byte 1 ( $A_0 = V_{IH}$ ,  $DQ_0 - DQ_7$ ), the device identifier code. These identifier bytes are given in Table 2. All identifiers for manufacturer and device codes will possess odd parity,

with the most significant bit (MSB),  $DQ_7$ , defined as the parity bit.

### Read Mode

AMD OTPROMs have two control functions, both of which must be logically satisfied in order to obtain data at the outputs. Chip Enable ( $\overline{CE}$ ) is the power control and should be used for device selection. Output Enable ( $\overline{OE}$ ) is the output control and should be used to gate data to the output pins, independent of device selection. Assuming that addresses are stable, address access time ( $t_{ACC}$ ) is equal to the delay from  $\overline{CE}$  to output ( $t_{CE}$ ). Data is available at the outputs  $t_{OE}$  after the falling edge of  $\overline{OE}$ , assuming that  $\overline{CE}$  has been LOW and addresses have been stable for at least  $t_{ACC} - t_{OE}$ .

### Standby Mode

AMD OTPROMs have a standby mode which reduces the active power dissipation up to 80%. The OTPROM is placed in the standby mode by applying a TTL HIGH signal to the  $\overline{CE}$  input. When in standby mode, the outputs are in a high-impedance state, independent of the  $\overline{OE}$  input.

### Output OR-Tieing

To accommodate multiple memory connections, a two-line control function is provided to allow for: 1) low-memory power dissipation, and 2) assurance that output-bus contention will not occur.

It is recommended that  $\overline{CE}$  be decoded and used as the primary device-selecting function, while  $\overline{OE}$  be made a common connection to all devices in the array, and connected to the Read line from the system control bus. This assures that all deselected memory devices are in their low-power standby mode and that the output pins are only active when data is desired from a particular memory device.

### Program Inhibit

Programming of multiple OTPROMs in parallel with different data is also easily accomplished. Except for  $\overline{CE}$  or  $\overline{PGM}$ , all like inputs (including  $\overline{OE}$  and  $V_{pp}$ ) of the parallel OTPROMs may be common. A TTL LOW-level program pulse applied to the  $\overline{PGM}$  ( $\overline{CE/PGM}$  for 256K) input with  $V_{pp}$  between 12.75 V and 13.25 V and  $\overline{CE}$  LOW, will program that OTPROM. A HIGH-level  $\overline{CE}$  or  $\overline{PGM}$  input inhibits the other OTPROMs from being programmed.

### Program Verify

A verify should be performed on the programmed bits to determine that they were correctly programmed.

Data for all the OTPROMs should be verified  $t_{OE}$  after the falling edge of  $\overline{OE}$ ,  $V_{pp}$  must be between 12.75 V and 13.25 V for all OTPROMs.

### System Applications

During the switch between active and standby conditions, transient current peaks are produced on the rising and falling edges of Chip Enable. The magnitude of these transient current peaks is dependent on the output capacitance loading of the device. A 0.1- $\mu$ F ceramic capacitor (high-frequency, low-inherent inductance) should be used on each device between  $V_{CC}$  and GND to minimize transient effects. In addition, to overcome the voltage drop caused by the inductive effects of the printed circuit-board traces on OTPROM arrays, a 4.7- $\mu$ F bulk electrolytic capacitor should be used between  $V_{CC}$  and GND for each eight devices. The location of the capacitor should be close to where the power supply is connected to the array.

## FUNCTION TABLES

**TABLE 1. Am2764A and 27128A MODE SELECT**

| MODE            | PINS | $\overline{CE}$ | $\overline{OE}$ | $\overline{PGM}$ | $A_9$ | $V_{pp}$ | OUTPUTS |
|-----------------|------|-----------------|-----------------|------------------|-------|----------|---------|
|                 |      |                 |                 |                  |       |          |         |
| Read            |      | L               | L               | H                | X     | $V_{CC}$ | DOUT    |
| Output Disable  |      | L               | H               | H                | X     | $V_{CC}$ | Hi-Z    |
| Standby         |      | H               | X               | X                | X     | $V_{CC}$ | Hi-Z    |
| Program         |      | L               | X               | L                | X     | $V_{pp}$ | DIN     |
| Program Verify  |      | L               | L               | H                | X     | $V_{pp}$ | DOUT    |
| Program Inhibit |      | H               | X               | X                | X     | $V_{pp}$ | Hi-Z    |
| Auto Select     |      | L               | L               | H                | $V_H$ | $V_{CC}$ | Code    |

**TABLE 2. Am27256 MODE SELECT**

| MODE            | PINS | $\overline{CE}/\overline{PGM}$ | $\overline{OE}$ | $A_9$ | $V_{pp}$ | OUTPUTS |
|-----------------|------|--------------------------------|-----------------|-------|----------|---------|
|                 |      |                                |                 |       |          |         |
| Read            |      | L                              | L               | X     | $V_{CC}$ | DOUT    |
| Output Disable  |      | L                              | H               | X     | $V_{CC}$ | Hi-Z    |
| Standby         |      | H                              | X               | X     | $V_{CC}$ | Hi-Z    |
| Program         |      | L                              | H               | X     | $V_{pp}$ | DIN     |
| Program Verify  |      | H                              | L               | X     | $V_{pp}$ | DOUT    |
| Program Inhibit |      | H                              | H               | X     | $V_{pp}$ | Hi-Z    |
| Auto Select     |      | L                              | L               | $V_H$ | $V_{CC}$ | Code    |

Key: L = LOW

H = HIGH

X = Can be either LOW or HIGH

$V_H = 12.0 \text{ V} \pm 0.5 \text{ V}$

## ABSOLUTE MAXIMUM RATINGS

Storage Temperature ..... -65 to +150°C  
 Ambient Temperature with Power Applied . -65 to +135°C  
 Supply Voltage  
     with respect to Ground  
     on all Inputs except Ag and Vpp ..... +6.50 to -0.6 V  
     on Ag ..... +13.50 to -0.6 V  
     on Vpp ..... +13.50 to -0.6 V

Stresses above those listed under ABSOLUTE MAXIMUM RATINGS may cause permanent device failure. Functionality at or above these limits is not implied. Exposure to absolute maximum ratings for extended periods may affect device reliability.

## OPERATING RANGES

Commercial (C) Devices

Temperature (T<sub>C</sub>) ..... 0 to +70°C  
 Supply Voltage (V<sub>CC</sub>) ..... (Notes 1 & 2)

Notes: 1. For -2, blank, and -4 versions, V<sub>CC</sub> = +4.75 to +5.25 V.  
 2. For -20 and -25 versions, V<sub>CC</sub> = +4.50 to +5.50 V.

Operating ranges define those limits between which the functionality of the device is guaranteed.

**DC CHARACTERISTICS** over operating range unless otherwise specified (Notes 1, 2, & 4)\*

| Parameter Symbol | Parameter Description                                   | Test Conditions                                        | Min. | Max.                | Units |
|------------------|---------------------------------------------------------|--------------------------------------------------------|------|---------------------|-------|
| V <sub>OH</sub>  | Output HIGH Voltage                                     | I <sub>OH</sub> = -400 μA                              | 2.4  |                     | V     |
| V <sub>OL</sub>  | Output LOW Voltage                                      | I <sub>OL</sub> = 2.1 mA                               |      | 0.45                | V     |
| V <sub>IH</sub>  | Input HIGH Voltage                                      |                                                        | 2.0  | V <sub>CC</sub> + 1 | V     |
| V <sub>IL</sub>  | Input LOW Voltage                                       |                                                        | -0.1 | +0.8                | V     |
| I <sub>LI</sub>  | Input Load Current                                      | V <sub>IN</sub> = 0 to +5.5 V                          |      | 10.0                | μA    |
| I <sub>LO</sub>  | Output Leakage Current                                  | V <sub>OUT</sub> = 0 to -5.5 V                         |      | 10.0                | μA    |
| I <sub>CC1</sub> | V <sub>CC</sub> Standby Current (Note 6)                | $\overline{CE} = V_{IH}$ ,<br>$\overline{OE} = V_{IL}$ |      | 25                  | mA    |
| I <sub>CC2</sub> | V <sub>CC</sub> Active Current for Am2764A              | $\overline{OE} = \overline{CE} = V_{IL}$               |      | 75                  | mA    |
|                  | V <sub>CC</sub> Active Current for Am27128A and Am27256 |                                                        |      | 100                 |       |
| I <sub>PP1</sub> | V <sub>pp</sub> Read Current (Notes 1 & 5)              | V <sub>pp</sub> = 5.5 V                                |      | 5                   | mA    |

Notes: See notes following the Capacitance table on next page.

\*See the last page of this spec for Group A Subgroup Testing information.

## CAPACITANCE (Notes 2 & 3)

| Parameter Symbol | Parameter Description | Test Conditions        | Typ. | Max. | Units |
|------------------|-----------------------|------------------------|------|------|-------|
| $C_{IN}$         | Input Capacitance     | $V_{IN} = 0\text{ V}$  | 4    | 7    | pF    |
| $C_{OUT}$        | Output Capacitance    | $V_{OUT} = 0\text{ V}$ | 8    | 12   | pF    |

Notes: 1.  $V_{CC}$  must be applied simultaneously or before  $V_{pp}$ , and removed simultaneously or after  $V_{CC}$ .

2. Typical values are for nominal supply voltages.

3. This parameter is only sampled and not 100% tested.

4. Caution: The OTPROMs must not be removed from or inserted into a socket or board when  $V_{pp}$  or  $V_{CC}$  is applied.

5.  $V_{pp}$  may be connected to  $V_{CC}$  directly except during programming. The supply would then be the sum of  $I_{CC}$  and  $I_{pp}$ .

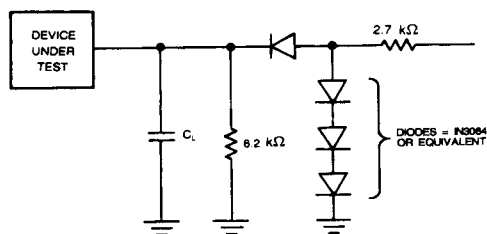
6.  $I_{CC1}$  Max. is 40 mA for -4 devices.

## KEY TO SWITCHING WAVEFORMS

| WAVEFORM | INPUTS                           | OUTPUTS                                   |
|----------|----------------------------------|-------------------------------------------|
|          | MUST BE STEADY                   | WILL BE STEADY                            |
|          | MAY CHANGE FROM H TO L           | WILL BE CHANGING FROM H TO L              |
|          | MAY CHANGE FROM L TO H           | WILL BE CHANGING FROM L TO H              |
|          | DON'T CARE; ANY CHANGE PERMITTED | CHANGING; STATE UNKNOWN                   |
|          | DOES NOT APPLY                   | CENTER LINE IS HIGH IMPEDANCE "OFF" STATE |

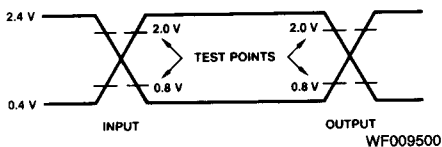
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## SWITCHING TEST CIRCUITS



TC003191

## SWITCHING TEST WAVEFORMS



WF009500

AC Testing: Inputs are driven at 2.4 V for a logic "1" and 0.45 V for a logic "0". Input pulse rise and fall times are  $\leq 20\text{ ns}$ .

# SWITCHING CHARACTERISTICS over operating range unless otherwise specified\* (Notes 1 & 3)

| No. | Parameter Symbol     | Parameter Description                                                                       | Test Conditions (Note 4)                 | -2, -20 |      | Blank, -25 |      | -4   |      | Units |
|-----|----------------------|---------------------------------------------------------------------------------------------|------------------------------------------|---------|------|------------|------|------|------|-------|
|     |                      |                                                                                             |                                          | Min.    | Max. | Min.       | Max. | Min. | Max. |       |
| 1   | $t_{ACC}$            | Address to Output Delay                                                                     | $\overline{CE} = \overline{OE} = V_{IL}$ |         | 200  |            | 250  |      | 450  | ns    |
| 2   | $t_{CE}$             | Chip Enable to Output Delay                                                                 |                                          |         | 200  |            | 250  |      | 450  | ns    |
| 3   | $t_{OE}$             | Output Enable to Output Delay                                                               |                                          |         | 75   |            | 100  |      | 150  | ns    |
| 4   | $t_{DF}$<br>(Note 2) | Output Enable HIGH to Output Float                                                          |                                          | 0       | 60   | 0          | 60   | 0    | 80   | ns    |
| 5   | $t_{OH}$<br>(Note 2) | Output Hold from Addresses, $\overline{CE}$ , or $\overline{OE}$ , whichever occurred first |                                          | 0       |      | 0          |      | 0    |      | ns    |

Notes: 1.  $V_{CC}$  must be applied simultaneously or before  $V_{pp}$ , and removed simultaneously or after  $V_{pp}$ .

2. This parameter is only sampled and not 100% tested.

3. Caution: The AMD 8-bit OTPROM Family must not be removed from or inserted into a socket or board when  $V_{pp}$  or  $V_{CC}$  is applied.

4. Output Load: 1 TTL gate and  $C_L = 100$  pF,

Input Rise and Fall Times:  $\leq 20$  ns,

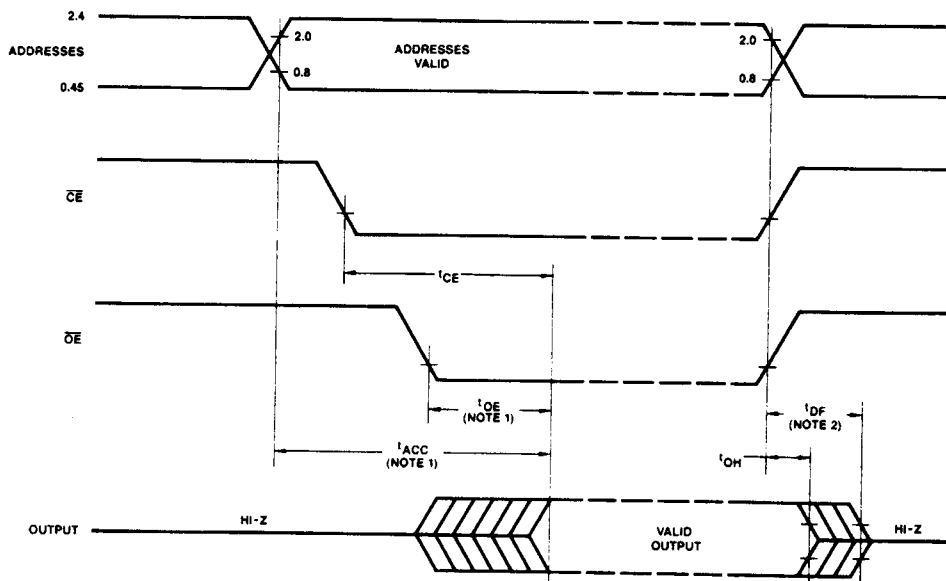
Input Pulse Levels: 0.45 to 2.4 V,

Timing Measurement Reference Level — Inputs: 1 V and 2 V

Outputs: 0.8 V and 2 V.

\*See the last page of this spec for Group A Subgroup Testing information.

## SWITCHING WAVEFORMS



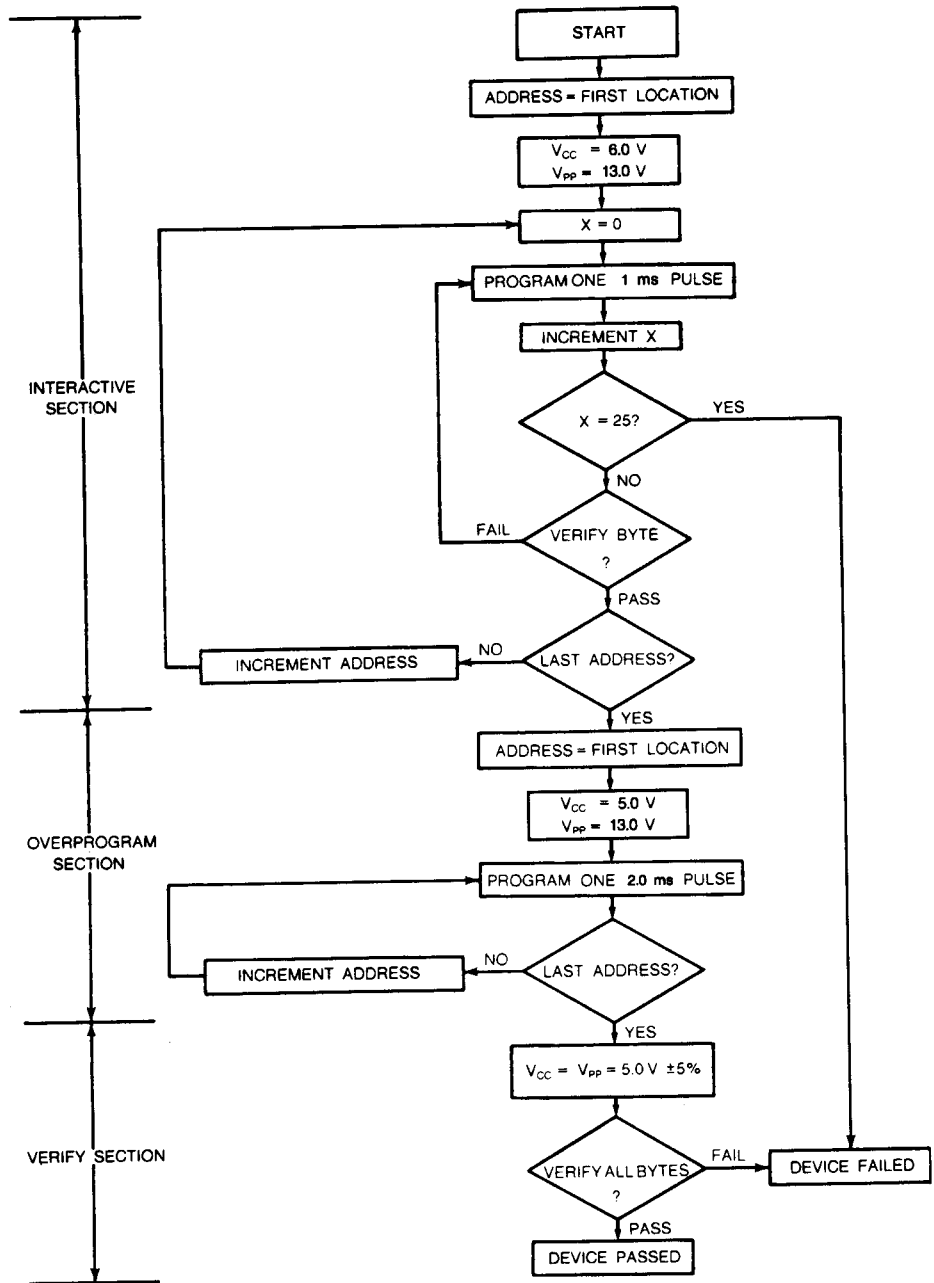
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Notes: 1.  $\overline{OE}$  may be delayed up to  $t_{ACC} - t_{OE}$  after the falling edge of  $\overline{OE}$  without impact on  $t_{ACC}$ .

2.  $t_{DF}$  is specified from  $\overline{OE}$  or  $\overline{CE}$ , whichever occurs first.

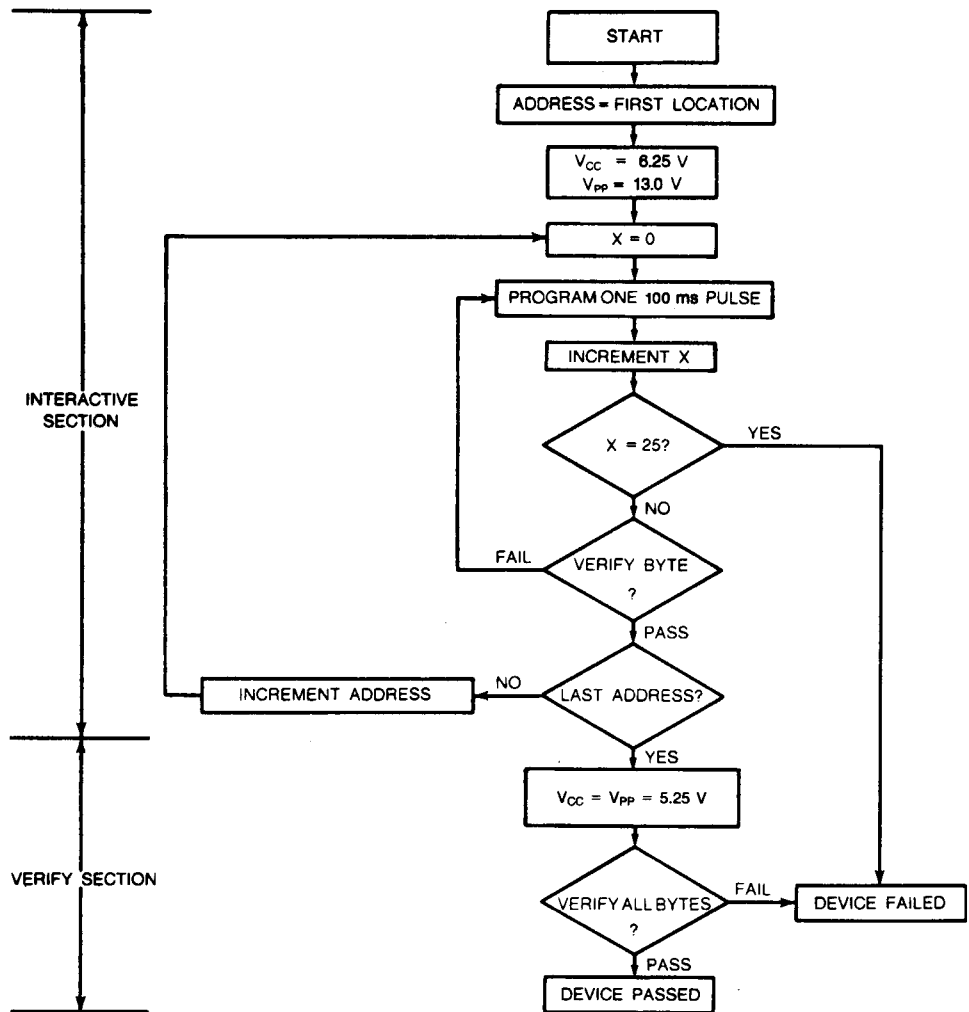
## PROGRAMMING

This section covers Identifier bytes, Interactive Programming Flowchart, and Programming DC and AC Switching Programming Characteristics.



PF000251

Figure 1. Interactive Programming Flow Chart



PF001725

Figure 2. Flashrite Programming Flow Chart

**TABLE 3. IDENTIFIER BYTES**

| Identifier \ Pins    | A <sub>0</sub>  | DQ <sub>7</sub> | DQ <sub>6</sub> | DQ <sub>5</sub> | DQ <sub>4</sub> | DQ <sub>3</sub> | DQ <sub>2</sub> | DQ <sub>1</sub> | DQ <sub>0</sub> | Hex Data |
|----------------------|-----------------|-----------------|-----------------|-----------------|-----------------|-----------------|-----------------|-----------------|-----------------|----------|
| Manufacturer Code    | V <sub>IL</sub> | 0               | 0               | 0               | 0               | 0               | 0               | 0               | 1               | 01       |
| Am2764A Device Code  | V <sub>IH</sub> | 0               | 0               | 0               | 0               | 1               | 0               | 0               | 0               | 08       |
| Am27128A Device Code | V <sub>IH</sub> | 1               | 0               | 0               | 0               | 1               | 0               | 0               | 1               | 89       |
| Am27256 Device Code  | V <sub>IH</sub> | 0               | 0               | 0               | 0               | 0               | 1               | 0               | 0               | 04       |

- Notes: 1. A<sub>9</sub> = 12.0 V  $\pm$ 0.5 V  
2. All other Address Lines =  $\overline{CE} = \overline{OE} = V_{IL}$   
3. For Am2764A, PGM = V<sub>IH</sub>  
4. For Am27256, A<sub>14</sub> = Don't Care

**INTERACTIVE PROGRAMMING ALGORITHM DC PROGRAMMING CHARACTERISTICS**

| Parameter Symbol | Parameter Description                               |                          | Test Conditions                                         | Min.  | Max.                | Units   |
|------------------|-----------------------------------------------------|--------------------------|---------------------------------------------------------|-------|---------------------|---------|
| I <sub>L1</sub>  | Input Current (All Inputs)                          |                          | V <sub>IN</sub> = V <sub>IL</sub> or V <sub>IH</sub>    |       | 10.0                | $\mu$ A |
| V <sub>IL</sub>  | Input LOW Level (All Inputs)                        |                          |                                                         | -0.1  | 0.8                 | V       |
| V <sub>IH</sub>  | Input HIGH Level                                    |                          |                                                         | 2.0   | V <sub>CC</sub> + 1 | V       |
| V <sub>OL</sub>  | Output LOW Voltage during Verify                    |                          | I <sub>OL</sub> = 2.1 mA                                |       | .45                 | V       |
| V <sub>OH</sub>  | Output LOW Voltage during Verify                    |                          | I <sub>OH</sub> = -400 $\mu$ A                          | 2.4   |                     | V       |
| I <sub>CC2</sub> | V <sub>CC</sub> Supply Current (Program and Verify) | For Am2764A              |                                                         |       | 75                  | mA      |
|                  |                                                     | For Am27128A and Am27256 |                                                         |       | 100                 |         |
| I <sub>PP3</sub> | V <sub>PP</sub> Supply Current (Program)            |                          | $\overline{CE} = V_{IL} =$<br>PGM = $\overline{CE}/PGM$ |       | 30                  | mA      |
| V <sub>ID</sub>  | A <sub>9</sub> Auto-Select Voltage                  |                          |                                                         | 11.5  | 12.5                | V       |
| V <sub>PP</sub>  | Interactive Programming Algorithm                   |                          |                                                         | 12.0  | 13.3                | V       |
|                  | Flashrite Programming Algorithm                     |                          |                                                         | 12.75 | 13.25               | V       |
| V <sub>CC</sub>  | Interactive Programming Algorithm                   |                          |                                                         | 5.75  | 6.25                | V       |
|                  | Flashrite Programming Algorithm                     |                          |                                                         | 6.0   | 6.5                 | V       |

## PROGRAMMING AC CHARACTERISTICS

(Notes 1, 2, 3, and 4)

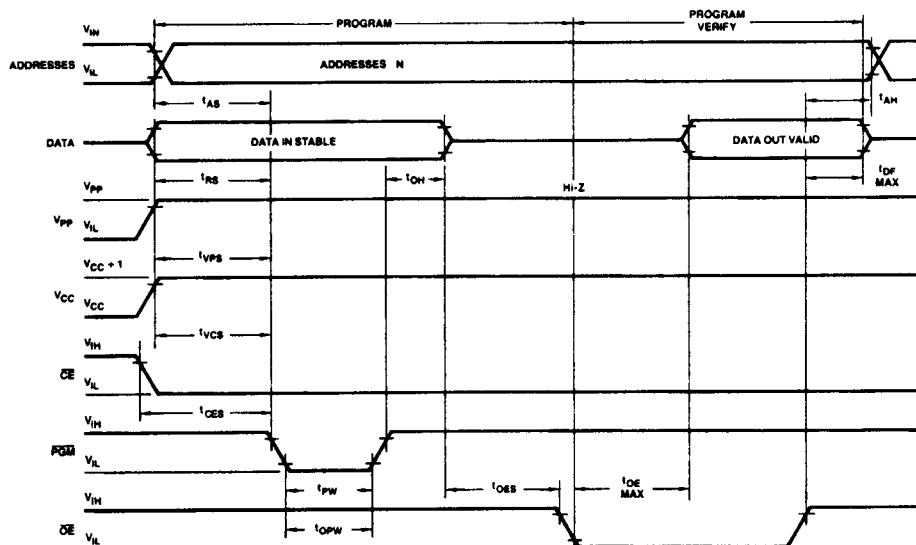
| No. | Parameter Symbols | Parameter Description                         | Min. | Max. | Units   |
|-----|-------------------|-----------------------------------------------|------|------|---------|
| 1   | $t_{AS}$          | Address Setup Time                            | 2    |      | $\mu s$ |
| 2   | $t_{OES}$         | $\overline{OE}$ Setup Time                    | 2    |      | $\mu s$ |
| 3   | $t_{DS}$          | Data Setup Time                               | 2    |      | $\mu s$ |
| 4   | $t_{AH}$          | Address Hold Time                             | 2    |      | $\mu s$ |
| 5   | $t_{DH}$          | Data Hold Time                                | 2    |      | $\mu s$ |
| 6   | $t_{DF}$          | Chip Enable to Output Float Delay             | 0    | 130  | $\mu s$ |
| 7   | $t_{VPS}$         | $V_{pp}$ Setup Time                           | 2.0  |      | $\mu s$ |
| 8   | $t_{VCS}$         | $V_{CC}$ Setup Time                           | 2    |      | $\mu s$ |
| 9   | $t_{PW}$          | PGM Initial Program Pulse Width (Interactive) | .95  | 1.05 | ms      |
|     |                   | PGM Initial Program Pulse Width (Flashrite)   | 95   | 105  | $\mu s$ |
| 10  | $t_{OPW}$         | PGM Overprogram Pulse Width (Note 3,5)        | 1.95 | 2.05 | ms      |
| 11  | $t_{CES}$         | $\overline{CE}$ Setup Time                    | 2    |      | $\mu s$ |
| 12  | $t_{OE}$          | Data Valid from $\overline{OE}$               |      | 150  | ns      |

- Notes: 1.  $T_A = +25^\circ C \pm 5^\circ C$ ; see DC Programming Characteristics for  $V_{CC}$  and  $V_{pp}$  voltages.  
2.  $V_{CC}$  must be applied simultaneously or before  $V_{pp}$  and removed simultaneously or after  $V_{pp}$ .  
3. When programming the OTPROM family, a 0.1- $\mu F$  capacitor is required across  $V_{pp}$  and ground to suppress spurious voltage transients which may damage the device.  
4. Programming characteristics are guidelines which must be followed. They are not 100% tested to worst-case limits.  
5. Interactive programming algorithm only.

## INTERACTIVE PROGRAMMING ALGORITHM WAVEFORMS

### Am2764A and Am27128A

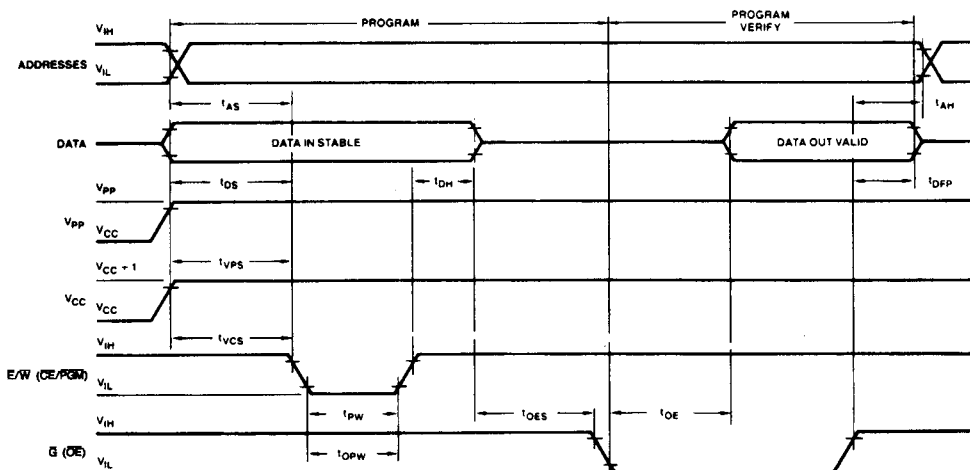
(Notes 1 and 2)



WF000552

### Am27256

(Notes 1 and 3)



WF000582

Notes: 1. The input timing reference level is 0.8 V for  $V_{IL}$  and 2 V for  $V_{IH}$ .

2.  $t_{OE}$  and  $t_{DF}$  are characteristics of the device, but must be accommodated by the programmer.

3.  $t_{OE}$  and  $t_{DFP}$  are characteristics of the device, but must be accommodated by the programmer.

## GROUP A SUBGROUP TESTING

### DC CHARACTERISTICS

| Parameter Symbol | Subgroups* |
|------------------|------------|
| V <sub>OH</sub>  | 1, 2, 3    |
| V <sub>OL</sub>  | 1, 2, 3    |
| V <sub>IH</sub>  | 1, 2, 3    |
| V <sub>IL</sub>  | 1, 2, 3    |
| I <sub>LI</sub>  | 1, 2, 3    |
| I <sub>LO</sub>  | 1, 2, 3    |
| I <sub>CC1</sub> | 1, 2, 3    |
| I <sub>CC2</sub> | 1, 2, 3    |
| I <sub>PP1</sub> | 1, 2, 3    |
| I <sub>PP2</sub> | 1, 2, 3    |
| C <sub>IN</sub>  | 4          |
| C <sub>OUT</sub> | 4          |
| C <sub>IN2</sub> | 4          |
| C <sub>IN3</sub> | 4          |

\*For DC Programming Characteristics, only Subgroup 1 applies.

### SWITCHING CHARACTERISTICS

| No. | Parameter Symbol | Subgroups |
|-----|------------------|-----------|
| 1   | t <sub>ACC</sub> | 9, 10, 11 |
| 2   | t <sub>CE</sub>  | 9, 10, 11 |
| 3   | t <sub>OE</sub>  | 9, 10, 11 |
| 4   | t <sub>DF</sub>  | 9         |
| 5   | t <sub>OH</sub>  | 9         |

### MILITARY BURN-IN

Military burn-in is in accordance with the current revision of MIL-STD-883, Test Method 1015, Conditions A through E. Test conditions are selected at AMD's option.